

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

TND316S

ExPD (Excellent Power Device)

General Purpose Driver for PDP Sustain Pulse Drive, Motor Drive, Switching Power Supply, and DC / DC Converter Applications

Features

- · Inverter buffer
- · Withstand voltage of 25V is assured
- · Peak output current: 1A

- Monolithic structure (High voltage CMOS process adopted)
- Wide range of operating voltage: 4.5V to 25V
- Fast switching time (30ns typical at 1000pF load)
- Fully compatible input to TTL / CMOS (V_{IH}=up to 2.6V, at V_{DD}=4.5 to 25V)
- · Built-in input pull-down resistance

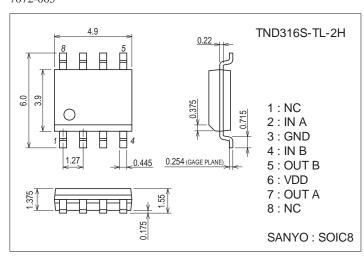
Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply Voltage	V _{DD}		0 to 25	V
Input Voltage	VIN		GND-0.3 to V _{DD} +0.3	V
Allowable Power Dissipation	P _D max		0.3	W
Junction Temperature	Tj		-55 to +150	C
Storage Temperature	Tstg		-55 to +150	C

Package Dimensions

unit : mm (typ) 7072-005

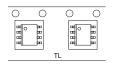


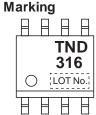
Product & Package Information

Package : SOIC8JEITA, JEDEC : SC-87, SOT-96

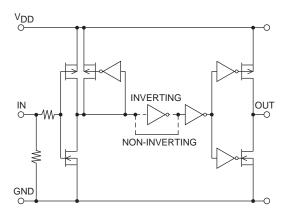
• Minimum Packing Quantity : 2,500 pcs./reel

Packing Type: TL





Block Diagram



Recommend Operating Conditions at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit	
Operating Supply Voltage	V _{DD}		4.5 to 25	V	Ì
Operating Temperature	Topr		-40 to +125	C]

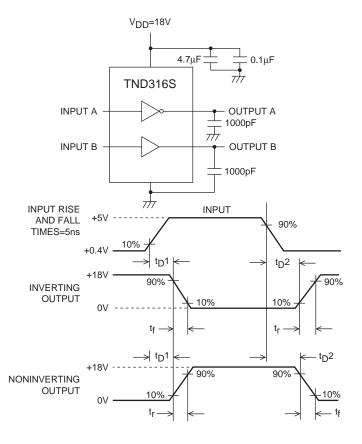
Electrical Characteristics (AC Characteristics) at Ta=25°C, V_{DD}=18V, V_{IN}=5V

Parameter	Symbol	Conditions	Ratings			Unit
Falanielei		Conditions	min	typ	max	Offic
Turn-On Rise Time	tr	C _L =1000pF		30	45	ns
Turn-Off Fall Time	tf	C _L =1000pF		30	45	ns
Delay Time	t _D 1	C _L =1000pF		30	45	ns
Delay Time	tD2	CL=1000pF		45	60	ns

Electrical Characteristics (DC Characteristics) at Ta=25°C, VDD=4.5 to 25V

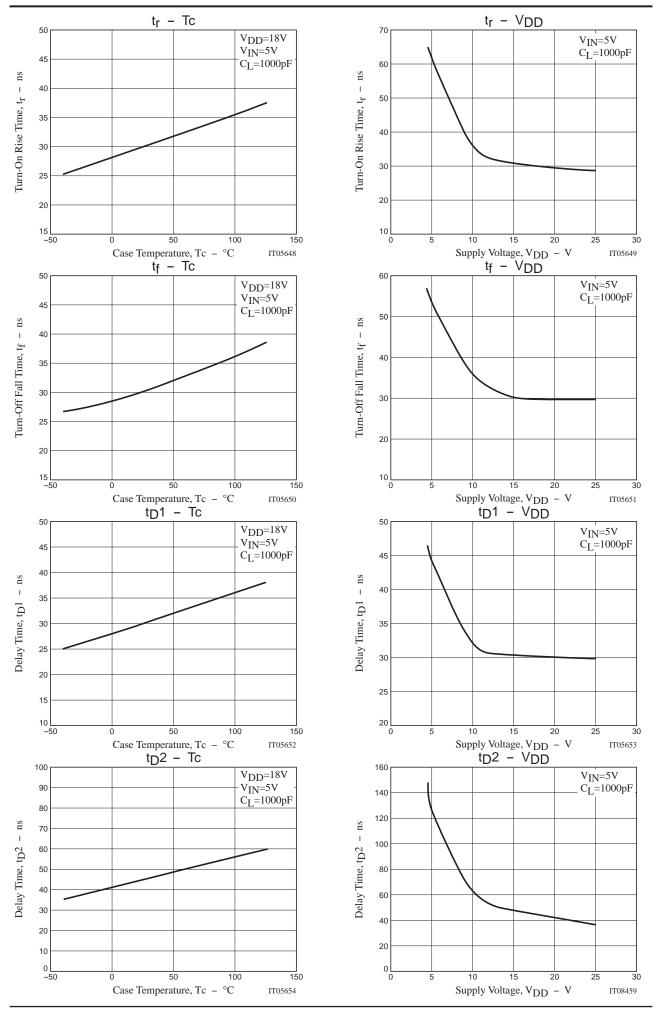
Parameter	Symbol	Conditions	Ratings			Unit	
Farameter	Syllibol	Conditions	min	typ	max	UTIIL	
Logic "1" Input Voltage	VIH		2.6			V	
Logic "0" Input Voltage	VIL				0.8	V	
Logic "1" Input Bias Current	I _{IN} +	V _{IN} =V _{DD} =25V		40	100	μΑ	
Logic "0" Input Bias Current I _{IN} -		V _{IN} =0V or V _{DD}	-1		1	μΑ	
High-level Output Voltage VOH		IO=0A	VDD-0.1			V	
Low-level Output Voltage	VOL	IO=0A			0.1	V	
Van Supply Current	Isupp	V _{DD} =10V, V _{IN} =3V, (both inputs)		1.0	4.5	mA	
V _{DD} Supply Current		V _{DD} =10V, V _{IN} =0V, (both inputs)			0.2	mA	
Output High Short Circuit Pulsed Current	IO+	V _{DD} =18V, PW≤10μs, V _{OUT} =0V		1.0		Α	
Output Low Short Circuit Pulsed Current IO-		V _{DD} =18V, PW≤10μs, V _{OUT} =18V		1.0		А	
Output On Resistance	DOLLT	V _{DD} =18V, Iload=10mA, V _{OUT} ="H"		8	12	Ω	
Output Off Resistance	ROUT	V _{DD} =18V, Iload=10mA, V _{OUT} ="L"		6	10	Ω	

Switching Time Test Circuit

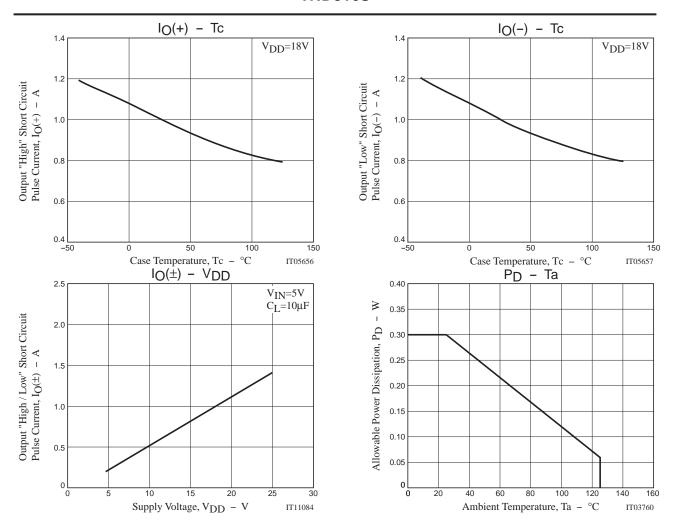


Ordering Information

Devices	Package	Shipping	memo	
TND316S-TL-2H	SOIC8	2,500pcs./reel	Pb Free and Halogen Free	



TND316S

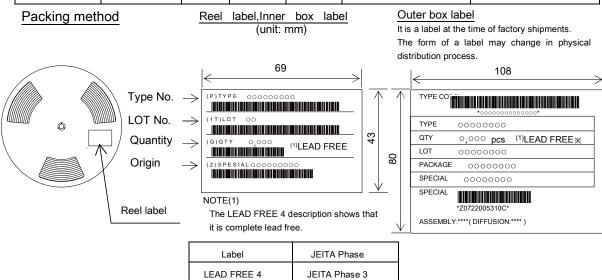


Taping Specification

TND316S-TL-2H

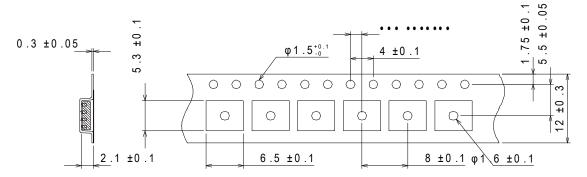
1. Packing Format

Package Name	Carrier Tape	Maximum Number of devices			Packing format		
	Туре	contained (pcs)					
		Reel	Inner box	Outer box	Inner BOX W206-112	Outer BOX W207-124	
SOIC8	B202-101	2,500	12,500	25,000	5 reels contained	2 inner boxes contained	
					Dimensions :mm(external)	Dimensions :mm(external)	
					340×95×340	360×210×375	

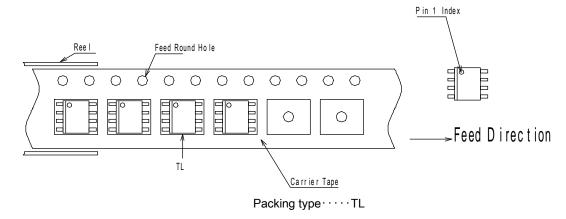


2. Taping configuration

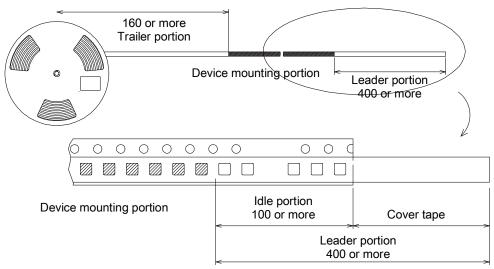
2-1. Carrier tape size (unit: mm)



2-2. Device placement direction



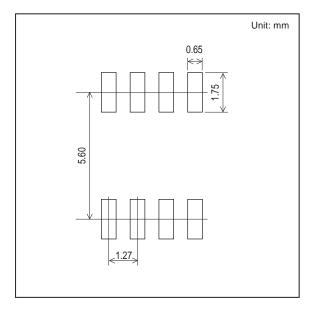
2-3. Leader portion and trailer portion (unit: mm)



Outline Drawing

TND316S-TL-2H

Land Pattern Example



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